NSN 5961-01-029-4558

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-029-4558 **Inclosure Material:** Plastic **Overall Length:** Between 0.234 inches and 0.246 inches **Terminal Length:** 0.990 inches **Overall Diameter:** Between 0.332 inches and 0.342 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 140.0 reverse voltage, total rms and 200.0 repetitive peak reverse voltage and 240.0 nonrepetitive peak reverse voltage and 200.0 working peak reverse voltage and 200.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 400.00 amperes forward current, average preset **Power Rating Per Characteristic:** 4.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No